TOSHIBA Transistor Silicon NPN Epitaxial Planar Type (PCT process)

2SC2715

High Frequency Amplifier Applications

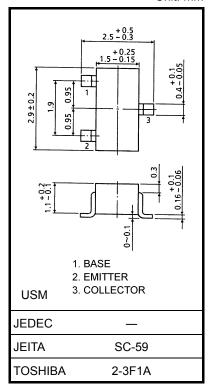
Unit: mm

- High power gain: Gpe = 30dB (typ.) (f = 10.7 MHz)
- Recommended for FM IF, OSC stage and AM CONV. IF stage.

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	35	V
Collector-emitter voltage	V _{CEO}	30	V
Emitter-base voltage	V _{EBO}	4	V
Collector current	IC	50	mA
Base current	I _B	10	mA
Collector power dissipation	PC	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Weight: 0.012 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 35 V, I _E = 0		_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 4 V, I _C = 0		_	1.0	μА
DC current gain	h _{FE} (Note)	V _{CE} = 12 V, I _C = 2 mA		_	240	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 10 mA, I _B = 1 mA		_	0.4	V
Base-emitter voltage	V _{BE}	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$	_	_	1.0	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 1 mA	100	_	400	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	2.0	3.2	pF
Collector-base time constant	C _c .rbb'	$V_{CE} = 10 \text{ V}, I_{E} = -1 \text{ mA}, f = 30 \text{ MHz}$	_	_	50	ps
Power gain	G _{pe}	$V_{CC} = 6 \text{ V}, I_E = -1 \text{ mA}, f = 10.7 \text{ MHz}$ (Figure 1)	27	30	33	dB

Note: hFE classification R: 40~80, O: 70~140, Y: 120~240

y Parameter (typ.)

(1) (common emitter f = 455 kHz, $Ta = 25^{\circ}\text{C}$)

Characteristics	Symbol	2SC2715-R	2SC2715-O	2SC2715-Y	Unit
Collector-emitter voltage	V _{CE}	6	6	6	V
Emitter current	ΙE	-1	-1	-1	mA
Input conductance	gie	0.58	0.41	0.26	mS
Input capacitance	C _{ie}	53	46	38	pF
Output conductance	9oe	1.9	2.7	4.8	μS
Output capacitance	C _{oe}	2.6	2.8	3.6	pF
Forward transfer admittance	y _{fe}	38	38	38	mS
Phase angle of forward transfer admittance	$\theta_{\sf fe}$	-0.79	-0.83	-0.92	٥
Reverse transfer admittance	y _{re}	5.7	5.7	6.2	μS
Phase angle of reverse transfer admittance	$\theta_{\sf re}$	-90	-90	-90	٥

(2) (common emitter f = 10.7 MHz, $Ta = 25^{\circ}\text{C}$)

Characteristics	Symbol	2SC2715-R	2SC2715-O	2SC2715-Y	Unit
Collector-emitter voltage	V _{CE}	6	6	6	V
Emitter current	ΙE	-1	-1	-1	mA
Input conductance	9ie	1.04	0.85	0.65	mS
Input capacitance	C _{ie}	49	43	36	pF
Output conductance	9oe	10	15	28	μS
Output capacitance	C _{oe}	2.7	2.9	3.6	pF
Forward transfer admittance	y _{fe}	37	37	37	mS
Phase angle of forward transfer admittance	θ _{fe}	-9.6	-10.4	-11.5	o
Reverse transfer admittance	y _{re}	120	120	140	μS
Phase angle of reverse transfer admittance	$\theta_{\sf re}$	-90	-90	-90	o

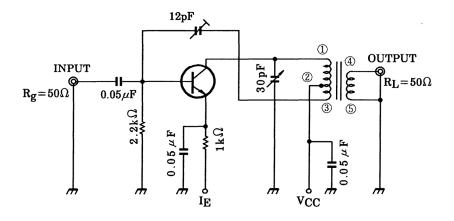
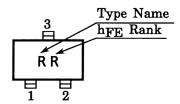


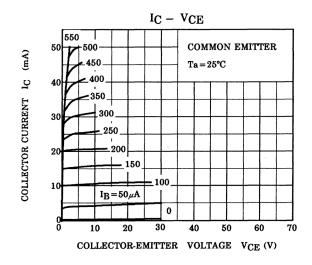
Figure 1 NF, Gpe Test Circuit

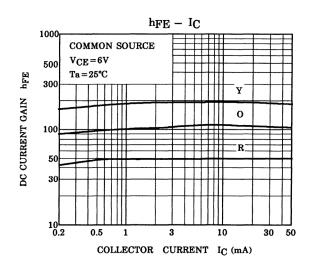
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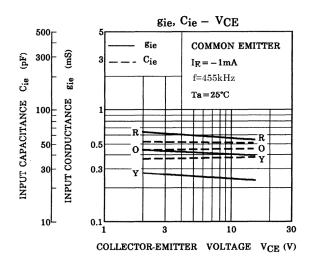
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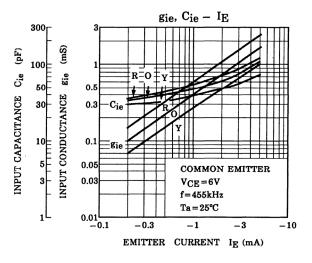


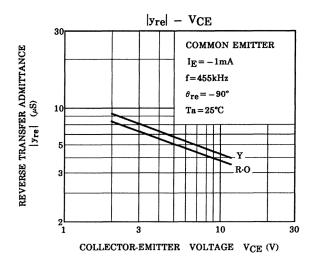
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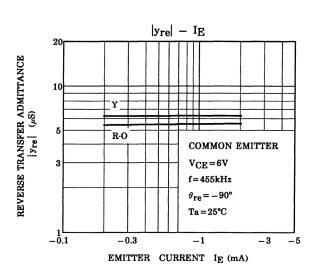


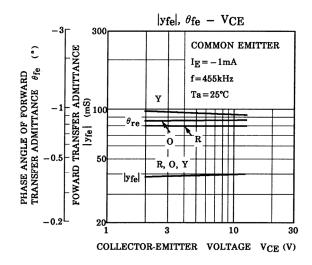


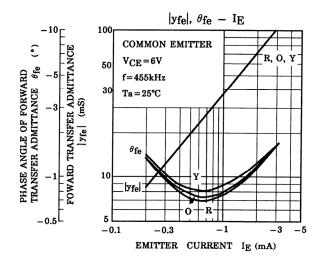


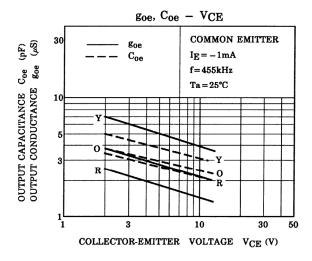


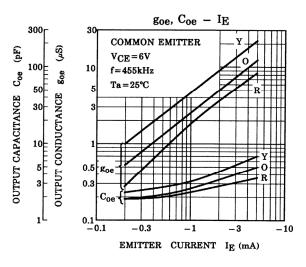


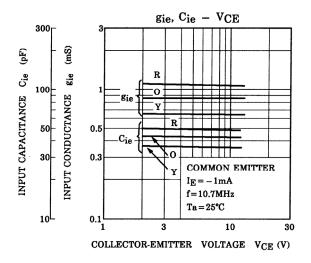


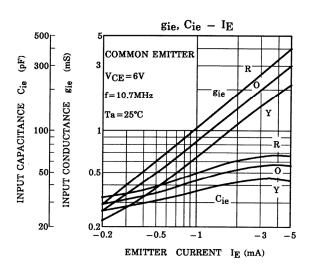




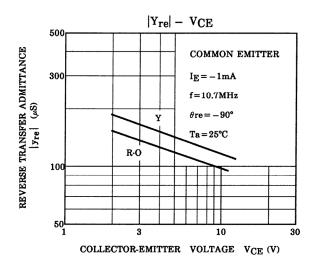


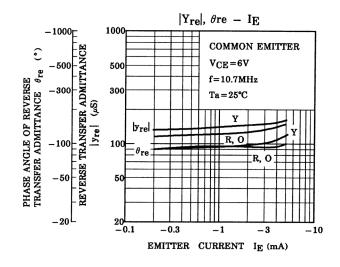


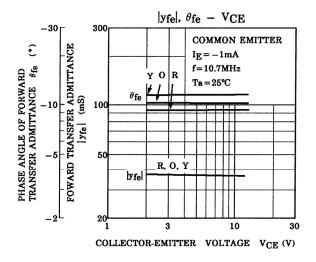


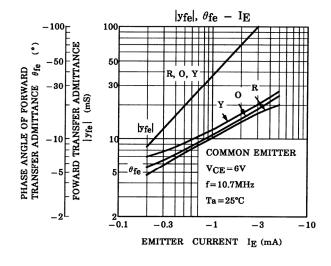


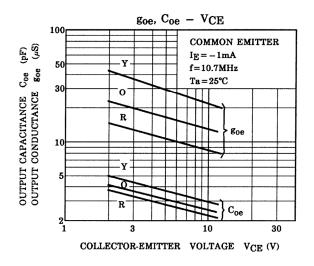
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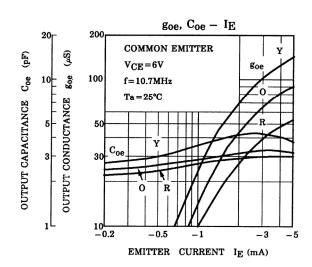


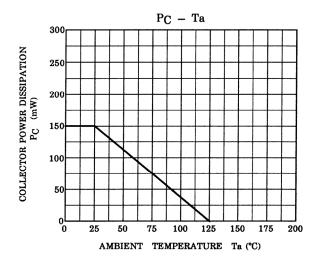












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